

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Rev. 03 — 7 February 2008

Product data sheet

1. General description

The 74AUP1G74 provides a low-power, low-voltage single positive-edge triggered D-type flip-flop with individual data (D), clock (CP), set (\bar{SD}) and reset (\bar{RD}) inputs and complementary Q and \bar{Q} outputs. The \bar{SD} and \bar{RD} are asynchronous active LOW inputs and operate independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D input must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114E Class 3A exceeds 5000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | Version |
|-------------|-------------------|--------|--|--|----------|
| | Temperature range | Name | Description | | |
| 74AUP1G74DC | –40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | | SOT765-1 |
| 74AUP1G74GT | –40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | | SOT833-1 |
| 74AUP1G74GM | –40 °C to +125 °C | XQFN8U | plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body 1.6 × 1.6 × 0.5 mm | | SOT902-1 |

4. Marking

Table 2. Marking codes

| Type number | Marking code |
|-------------|--------------|
| 74AUP1G74DC | p74 |
| 74AUP1G74GT | p74 |
| 74AUP1G74GM | p74 |

5. Functional diagram

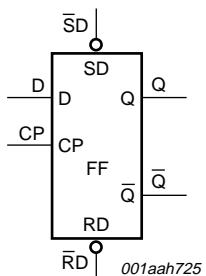


Fig 1. Logic symbol

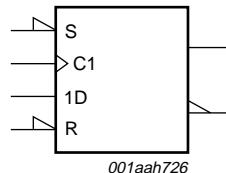


Fig 2. IEC logic symbol

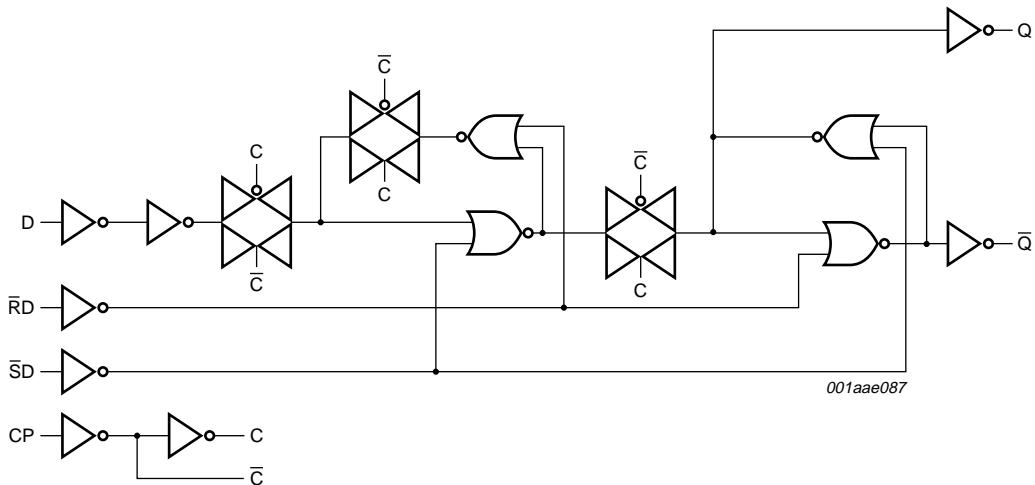


Fig 3. Logic diagram

6. Pinning information

6.1 Pinning

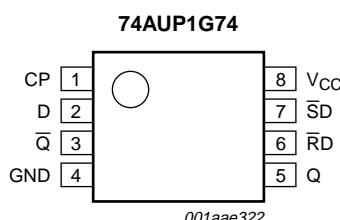


Fig 4. Pin configuration SOT765-1 (VSSOP8)

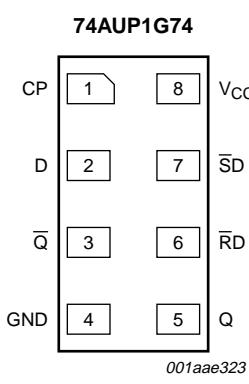


Fig 5. Pin configuration SOT833-1 (XSON8)

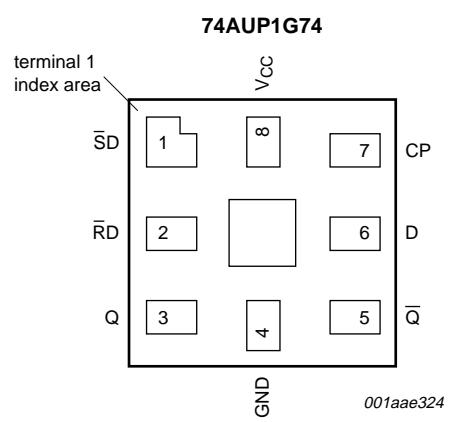


Fig 6. Pin configuration SOT902-1 (XQFN8U)

6.2 Pin description

Table 3. Pin description

| Symbol | Pin | | Description |
|------------|-----------------------|----------|---------------------------------------|
| | SOT765-1 and SOT833-1 | SOT902-1 | |
| CP | 1 | 7 | clock input |
| D | 2 | 6 | data input |
| \bar{Q} | 3 | 5 | complement output |
| GND | 4 | 4 | ground (0 V) |
| Q | 5 | 3 | true output |
| $\bar{R}D$ | 6 | 2 | asynchronous reset input (active LOW) |
| $\bar{S}D$ | 7 | 1 | asynchronous set input (active LOW) |
| V_{CC} | 8 | 8 | supply voltage |

7. Functional description

Table 4. Function table for asynchronous operation^[1]

| Input | | | | Output | |
|------------|------------|----|---|--------|-----------|
| $\bar{S}D$ | $\bar{R}D$ | CP | D | Q | \bar{Q} |
| L | H | X | X | H | L |
| H | L | X | X | L | H |
| L | L | X | X | H | H |

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

Table 5. Function table for synchronous operation^[1]

| Input | | | | Output | |
|------------|------------|----|---|-----------|-----------------|
| $\bar{S}D$ | $\bar{R}D$ | CP | D | Q_{n+1} | \bar{Q}_{n+1} |
| H | H | ↑ | L | L | H |
| H | H | ↑ | H | H | L |

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

↑ = LOW-to-HIGH CP transition;

Q_{n+1} = state after the next LOW-to-HIGH CP transition.

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|----------|------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| V _I | input voltage | | [1] -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| V _O | output voltage | Active mode and Power-down mode | [1] -0.5 | +4.6 | V |
| I _O | output current | V _O = 0 V to V _{CC} | - | ±20 | mA |
| I _{CC} | supply current | | - | +50 | mA |
| I _{GND} | ground current | | -50 | - | mA |
| T _{STG} | storage temperature | | -65 | +150 | °C |
| P _{TOT} | total power dissipation | T _{amb} = -40 °C to +125 °C | [2] - | 250 | mW |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of P_{TOT} derates linearly with 8.0 mW/K.

For XSON8 and XQFN8U packages: above 45 °C the value of P_{TOT} derates linearly with 2.4 mW/K.

9. Recommended operating conditions

Table 7. Operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|--|-----|-----------------|------|
| V _{CC} | supply voltage | | 0.8 | 3.6 | V |
| V _I | input voltage | | 0 | 3.6 | V |
| V _O | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V _{CC} = 0 V | 0 | 3.6 | V |
| T _{AMB} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 0.8 V to 3.6 V | - | 200 | ns/V |

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|--------------------------|-----------------------------------|------------------------|-----|------------------------|------|
| T_{AMB} = 25 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|--------------------------------------|---|------------------------|-----|------------------------|------|
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.75 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.11 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.32 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 2.05 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.9 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.72 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.6 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.31 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.31 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.31 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.44 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.31 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.44 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.1 | µA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.2 | µA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.2 | µA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 0.5 | µA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V; per pin | [1] | - | 40 | µA |
| C _I | input capacitance | V _{CC} = 0 V to 3.6 V; V _I = GND or V _{CC} | - | 0.6 | - | pF |
| C _O | output capacitance | V _O = GND; V _{CC} = 0 V | - | 1.3 | - | pF |
| T_{amb} = -40 °C to +85 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------|--------------------------------------|--|-----------------------|-----|-----------------------|------|
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.7 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.03 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.30 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.97 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.85 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.67 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.37 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.33 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.5 | µA |
| | | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.5 | µA |
| ΔI _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.6 | µA |
| ΔI _{CC} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.6 | µA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 0.9 | µA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V; per pin | [1] | - | 50 | µA |

T_{amb} = -40 °C to +125 °C

| | | | | | | |
|-----------------|--------------------------|-----------------------------------|------------------------|---|------------------------|---|
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.75 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.25 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------|--------------------------------------|---|------------------------|-----|------------------------|------|
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.6 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 0.93 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.17 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.77 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.67 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.40 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.30 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.11 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.33 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.41 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.39 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.36 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.50 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.36 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.50 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.75 | µA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.75 | µA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.75 | µA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 1.4 | µA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V; per pin | [1] | - | 75 | µA |

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 9. Dynamic characteristicsVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +125 °C | | | | Unit |
|-----------------------------|-------------------|---|-------|--------------------|------|-------------------|-------------|-----|--------------|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Min | Max (125 °C) | |
| C_L = 5 pF | | | | | | | | | | |
| t _{pd} | propagation delay | CP to Q, \bar{Q} ; see Figure 7 [2] | | | | | | | | |
| | | V _{CC} = 0.8 V | - | 25.4 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.9 | 6.7 | 14.0 | 2.6 | 14.2 | 2.6 | 14.2 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.4 | 4.5 | 7.6 | 2.3 | 8.3 | 2.3 | 8.6 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.9 | 3.5 | 5.7 | 1.7 | 6.5 | 1.7 | 6.8 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | 2.6 | 3.8 | 1.4 | 4.4 | 1.4 | 4.7 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.5 | 2.2 | 3.1 | 1.2 | 3.4 | 1.2 | 3.7 | ns |
| | | SD to Q, \bar{Q} ; see Figure 8 [2] | | | | | | | | |
| | | V _{CC} = 0.8 V | - | 19.6 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.7 | 5.6 | 11.0 | 2.5 | 11.4 | 2.5 | 11.5 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.4 | 4.0 | 6.3 | 2.2 | 6.9 | 2.2 | 7.3 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.0 | 3.3 | 4.9 | 1.7 | 5.6 | 1.7 | 5.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.9 | 2.7 | 3.7 | 1.7 | 4.0 | 1.7 | 4.2 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.8 | 2.5 | 3.2 | 1.5 | 3.6 | 1.5 | 3.8 | ns |
| | | RD to Q, \bar{Q} ; see Figure 8 [2] | | | | | | | | |
| | | V _{CC} = 0.8 V | - | 19.2 | - | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.6 | 5.5 | 11.0 | 2.5 | 11.3 | 2.5 | 11.5 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.3 | 3.9 | 6.3 | 2.2 | 6.8 | 2.2 | 7.3 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.9 | 3.2 | 5.0 | 1.8 | 5.6 | 1.8 | 5.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.9 | 2.6 | 3.6 | 1.7 | 4.1 | 1.7 | 4.3 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.8 | 2.4 | 3.3 | 1.5 | 3.6 | 1.5 | 3.8 | ns |
| f _{max} | maximum frequency | CP; see Figure 8 | | | | | | | | |
| | | V _{CC} = 0.8 V | - | 53 | - | - | - | - | - | MHz |
| | | V _{CC} = 1.1 V to 1.3 V | - | 203 | - | 170 | - | 170 | - | MHz |
| | | V _{CC} = 1.4 V to 1.6 V | - | 347 | - | 310 | - | 300 | - | MHz |
| | | V _{CC} = 1.65 V to 1.95 V | - | 435 | - | 400 | - | 390 | - | MHz |
| | | V _{CC} = 2.3 V to 2.7 V | - | 550 | - | 490 | - | 480 | - | MHz |
| | | V _{CC} = 3.0 V to 3.6 V | - | 619 | - | 550 | - | 510 | - | MHz |

Table 9. Dynamic characteristics ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +125 °C | | | Unit |
|------------------------------|---|---|-------|--------------------|------|-------------------|-------------|-----|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Min | |
| C_L = 10 pF | | | | | | | | | |
| t _{pd} | propagation delay | CP to Q, \bar{Q} ; see Figure 7 [2] | - | 28.9 | - | - | - | - | ns |
| | | V _{CC} = 0.8 V | - | 28.9 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.1 | 7.5 | 15.8 | 2.9 | 16.1 | 2.9 | 16.1 |
| | | V _{CC} = 1.4 V to 1.6 V | 2.7 | 5.1 | 8.7 | 2.4 | 9.4 | 2.4 | 9.8 |
| | | V _{CC} = 1.65 V to 1.95 V | 2.5 | 4.1 | 6.5 | 2.2 | 7.2 | 2.2 | 7.6 |
| | | V _{CC} = 2.3 V to 2.7 V | 2.0 | 3.2 | 4.6 | 1.8 | 5.3 | 1.8 | 5.6 |
| | SD to Q, \bar{Q} ; see Figure 8 [2] | V _{CC} = 3.0 V to 3.6 V | 1.8 | 2.8 | 3.8 | 1.6 | 4.1 | 1.6 | 4.4 |
| | | V _{CC} = 0.8 V | - | 23.2 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.9 | 6.5 | 12.9 | 2.8 | 13.3 | 2.8 | 13.5 |
| | | V _{CC} = 1.4 V to 1.6 V | 2.7 | 4.6 | 7.5 | 2.3 | 7.9 | 2.3 | 8.3 |
| | | V _{CC} = 1.65 V to 1.95 V | 2.6 | 3.9 | 5.6 | 2.3 | 6.3 | 2.3 | 6.6 |
| | | V _{CC} = 2.3 V to 2.7 V | 2.3 | 3.2 | 4.4 | 2.0 | 4.8 | 2.0 | 5.2 |
| | $\bar{R}D$ to Q, \bar{Q} ; see Figure 8 [2] | V _{CC} = 3.0 V to 3.6 V | 2.2 | 3.0 | 3.9 | 1.9 | 4.2 | 1.9 | 4.4 |
| | | V _{CC} = 0.8 V | - | 22.7 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.8 | 6.4 | 12.8 | 2.7 | 13.2 | 2.7 | 13.4 |
| | | V _{CC} = 1.4 V to 1.6 V | 2.6 | 4.5 | 7.5 | 2.3 | 8.1 | 2.3 | 8.4 |
| | | V _{CC} = 1.65 V to 1.95 V | 2.5 | 3.3 | 5.8 | 2.3 | 6.3 | 2.3 | 6.7 |
| | | V _{CC} = 2.3 V to 2.7 V | 2.2 | 3.2 | 4.4 | 2.0 | 4.9 | 2.0 | 5.2 |
| | f _{max} | V _{CC} = 3.0 V to 3.6 V | 2.0 | 2.9 | 4.0 | 1.9 | 4.3 | 1.9 | 4.5 |
| | | CP; see Figure 8 | - | - | - | - | - | - | MHz |
| | | V _{CC} = 0.8 V | - | 52 | - | - | - | - | MHz |
| | | V _{CC} = 1.1 V to 1.3 V | - | 192 | - | 150 | - | 150 | MHz |
| | | V _{CC} = 1.4 V to 1.6 V | - | 324 | - | 280 | - | 230 | MHz |
| | | V _{CC} = 1.65 V to 1.95 V | - | 421 | - | 310 | - | 250 | MHz |
| | | V _{CC} = 2.3 V to 2.7 V | - | 486 | - | 370 | - | 360 | MHz |
| | | V _{CC} = 3.0 V to 3.6 V | - | 550 | - | 410 | - | 360 | MHz |

Table 9. Dynamic characteristics ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +125 °C | | | Unit | |
|------------------------------|---|---|----------------------------------|--------------------|------|-------------------|----------------|-----|------|--|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Min | | |
| C_L = 15 pF | | | | | | | | | | |
| t _{pd} | propagation delay | CP to Q, \bar{Q} ; see Figure 7 | ^[2] | | | | | | | |
| | | V _{CC} = 0.8 V | - | 32.4 | - | - | - | - | ns | |
| | | V _{CC} = 1.1 V to 1.3 V | 3.5 | 8.3 | 17.6 | 3.3 | 17.8 | 3.3 | 18.0 | |
| | | V _{CC} = 1.4 V to 1.6 V | 3.2 | 5.6 | 9.5 | 2.8 | 10.5 | 2.8 | 11.1 | |
| | | V _{CC} = 1.65 V to 1.95 V | 2.7 | 4.6 | 7.2 | 2.5 | 8.1 | 2.5 | 8.6 | |
| | | V _{CC} = 2.3 V to 2.7 V | 2.4 | 3.6 | 5.2 | 2.2 | 5.8 | 2.2 | 6.2 | |
| | SD to Q, \bar{Q} ; see Figure 8 | V _{CC} = 3.0 V to 3.6 V | 2.2 | 3.2 | 4.4 | 2.0 | 4.9 | 2.0 | 5.2 | |
| | | V _{CC} = 0.8 V | - | 26.7 | - | - | - | - | ns | |
| | | V _{CC} = 1.1 V to 1.3 V | 3.3 | 7.3 | 14.7 | 3.1 | 15.2 | 3.1 | 15.4 | |
| | | V _{CC} = 1.4 V to 1.6 V | 3.2 | 5.2 | 8.3 | 2.9 | 9.0 | 2.9 | 9.5 | |
| | | V _{CC} = 1.65 V to 1.95 V | 2.8 | 4.3 | 6.4 | 2.5 | 7.1 | 2.5 | 7.5 | |
| | | V _{CC} = 2.3 V to 2.7 V | 2.8 | 3.7 | 5.1 | 2.2 | 5.5 | 2.2 | 5.8 | |
| | $\bar{R}D$ to Q, \bar{Q} ; see Figure 8 | V _{CC} = 3.0 V to 3.6 V | 2.5 | 3.5 | 4.6 | 2.4 | 5.0 | 2.4 | 5.2 | |
| | | V _{CC} = 0.8 V | - | 26.1 | - | - | - | - | ns | |
| | | V _{CC} = 1.1 V to 1.3 V | 3.2 | 7.2 | 14.5 | 3.1 | 15.0 | 3.1 | 15.2 | |
| | | V _{CC} = 1.4 V to 1.6 V | 3.1 | 5.1 | 8.4 | 2.7 | 9.2 | 2.7 | 9.7 | |
| | | V _{CC} = 1.65 V to 1.95 V | 2.7 | 4.3 | 6.5 | 2.6 | 7.3 | 2.6 | 7.7 | |
| | | V _{CC} = 2.3 V to 2.7 V | 2.6 | 3.6 | 5.0 | 2.4 | 5.5 | 2.4 | 5.8 | |
| | f _{max} | CP; see Figure 8 | V _{CC} = 3.0 V to 3.6 V | 2.4 | 3.4 | 4.6 | 2.3 | 5.0 | 2.3 | |
| | | V _{CC} = 0.8 V | - | 50 | - | - | - | - | MHz | |
| | | V _{CC} = 1.1 V to 1.3 V | - | 181 | - | 120 | - | 120 | - | |
| | | V _{CC} = 1.4 V to 1.6 V | - | 301 | - | 190 | - | 160 | - | |
| | | V _{CC} = 1.65 V to 1.95 V | - | 407 | - | 240 | - | 190 | - | |
| | | V _{CC} = 2.3 V to 2.7 V | - | 422 | - | 300 | - | 270 | - | |
| | | V _{CC} = 3.0 V to 3.6 V | - | 481 | - | 320 | - | 300 | - | |

Table 9. Dynamic characteristics ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +125 °C | | | Unit |
|------------------------------|---|---|-------|--------------------|------|-------------------|----------------|-----|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Min | |
| C_L = 30 pF | | | | | | | | | |
| t _{pd} | propagation delay | CP to Q, \bar{Q} ; see Figure 7 [2] | | | | | | | |
| | | V _{CC} = 0.8 V | - | 42.7 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 4.2 | 10.6 | 22.5 | 4.0 | 23.0 | 4.0 | 23.3 |
| | | V _{CC} = 1.4 V to 1.6 V | 3.7 | 7.2 | 12.0 | 3.7 | 13.3 | 3.7 | 14.0 |
| | | V _{CC} = 1.65 V to 1.95 V | 3.5 | 5.8 | 9.2 | 3.4 | 10.4 | 3.4 | 11.0 |
| | | V _{CC} = 2.3 V to 2.7 V | 3.3 | 4.7 | 6.6 | 3.0 | 7.3 | 3.0 | 7.8 |
| | SD to Q, \bar{Q} ; see Figure 8 [2] | V _{CC} = 3.0 V to 3.6 V | 3.0 | 4.3 | 5.8 | 2.8 | 6.8 | 2.8 | 7.3 |
| | | V _{CC} = 0.8 V | - | 37.0 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 4.0 | 9.5 | 19.8 | 3.8 | 20.8 | 3.8 | 21.1 |
| | | V _{CC} = 1.4 V to 1.6 V | 3.8 | 6.7 | 10.9 | 3.7 | 12.0 | 3.7 | 12.7 |
| | | V _{CC} = 1.65 V to 1.95 V | 3.7 | 5.6 | 8.4 | 3.5 | 9.3 | 3.5 | 9.9 |
| | | V _{CC} = 2.3 V to 2.7 V | 3.7 | 4.8 | 6.6 | 3.2 | 7.2 | 3.2 | 7.6 |
| | $\bar{R}D$ to Q, \bar{Q} ; see Figure 8 [2] | V _{CC} = 3.0 V to 3.6 V | 3.4 | 4.6 | 6.0 | 3.1 | 6.8 | 3.1 | 7.1 |
| | | V _{CC} = 0.8 V | - | 36.4 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.9 | 9.4 | 19.5 | 3.8 | 20.2 | 3.8 | 20.5 |
| | | V _{CC} = 1.4 V to 1.6 V | 3.6 | 6.6 | 10.9 | 3.7 | 12.0 | 3.7 | 12.6 |
| | | V _{CC} = 1.65 V to 1.95 V | 3.5 | 5.5 | 8.5 | 3.5 | 9.5 | 3.5 | 10.1 |
| | | V _{CC} = 2.3 V to 2.7 V | 3.5 | 4.7 | 6.5 | 3.2 | 7.1 | 3.2 | 7.6 |
| | f _{max} | V _{CC} = 3.0 V to 3.6 V | 3.3 | 4.4 | 6.1 | 3.1 | 7.1 | 3.1 | 7.5 |
| | | CP; see Figure 8 | | | | | | | |
| | | V _{CC} = 0.8 V | - | 28 | - | - | - | - | MHz |
| | | V _{CC} = 1.1 V to 1.3 V | - | 145 | - | 70 | - | 70 | - |
| | | V _{CC} = 1.4 V to 1.6 V | - | 185 | - | 120 | - | 110 | - |
| | | V _{CC} = 1.65 V to 1.95 V | - | 270 | - | 150 | - | 120 | - |
| | | V _{CC} = 2.3 V to 2.7 V | - | 290 | - | 190 | - | 170 | - |
| | | V _{CC} = 3.0 V to 3.6 V | - | 315 | - | 200 | - | 190 | - |

Table 9. Dynamic characteristics ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +125 °C | | | Unit |
|---|---------------|---|-------|--------------------|-----|-------------------|----------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Min | |
| C_L = 5 pF, 10 pF, 15 pF and 30 pF | | | | | | | | | |
| t _{su} | set-up time | D to CP HIGH; see Figure 7 | | | | | | | |
| | | V _{CC} = 0.8 V | - | 3.4 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | - | 0.6 | - | 1.2 | - | 1.2 | - |
| | | V _{CC} = 1.4 V to 1.6 V | - | 0.3 | - | 0.6 | - | 0.6 | - |
| | | V _{CC} = 1.65 V to 1.95 V | - | 0.4 | - | 0.5 | - | 0.5 | - |
| | | V _{CC} = 2.3 V to 2.7 V | - | 0.2 | - | 0.4 | - | 0.4 | - |
| | | V _{CC} = 3.0 V to 3.6 V | - | 0.3 | - | 0.4 | - | 0.4 | - |
| | | D to CP LOW; see Figure 7 | | | | | | | |
| | | V _{CC} = 0.8 V | - | 3.0 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | - | 0.5 | - | 1.2 | - | 1.2 | - |
| | | V _{CC} = 1.4 V to 1.6 V | - | 0.3 | - | 0.7 | - | 0.7 | - |
| | | V _{CC} = 1.65 V to 1.95 V | - | 0.4 | - | 0.7 | - | 0.7 | - |
| | | V _{CC} = 2.3 V to 2.7 V | - | 0.5 | - | 0.7 | - | 0.7 | - |
| | | V _{CC} = 3.0 V to 3.6 V | - | 0.6 | - | 0.8 | - | 0.8 | - |
| t _h | hold time | D to CP; see Figure 7 | | | | | | | |
| | | V _{CC} = 0.8 V | - | −1.9 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | - | −0.3 | - | 0.5 | - | 0.5 | - |
| | | V _{CC} = 1.4 V to 1.6 V | - | −0.2 | - | 0.2 | - | 0.2 | - |
| | | V _{CC} = 1.65 V to 1.95 V | - | −0.2 | - | 0.1 | - | 0.1 | - |
| | | V _{CC} = 2.3 V to 2.7 V | - | −0.2 | - | 0.1 | - | 0.1 | - |
| | | V _{CC} = 3.0 V to 3.6 V | - | −0.2 | - | 0.1 | - | 0.1 | - |
| t _{rec} | recovery time | RD; see Figure 8 | | | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | - | −0.5 | - | −0.9 | - | −0.9 | - |
| | | V _{CC} = 1.4 V to 1.6 V | - | −0.2 | - | −0.6 | - | −0.6 | - |
| | | V _{CC} = 1.65 V to 1.95 V | - | −0.2 | - | −0.4 | - | −0.4 | - |
| | | V _{CC} = 2.3 V to 2.7 V | - | −0.1 | - | −0.1 | - | −0.1 | - |
| | | V _{CC} = 3.0 V to 3.6 V | - | −0.1 | - | −0.1 | - | −0.1 | - |
| | | SD; see Figure 8 | | | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | - | −0.5 | - | −0.3 | - | −0.3 | - |
| | | V _{CC} = 1.4 V to 1.6 V | - | −0.4 | - | −0.1 | - | −0.1 | - |
| | | V _{CC} = 1.65 V to 1.95 V | - | −0.3 | - | 0 | - | 0 | - |
| | | V _{CC} = 2.3 V to 2.7 V | - | −0.2 | - | 0.1 | - | 0.1 | - |
| | | V _{CC} = 3.0 V to 3.6 V | - | −0.1 | - | 0.1 | - | 0.1 | - |

Table 9. Dynamic characteristics ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +125 °C | | | Unit |
|-----------------|-------------------------------|---|----------------|--------------------|-----|-------------------|-------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Min | |
| t _W | pulse width | CP HIGH or LOW; see Figure 7 | | | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | - | 2.1 | - | 2.7 | - | 2.7 | - ns |
| | | V _{CC} = 1.4 V to 1.6 V | - | 1.1 | - | 1.5 | - | 1.5 | - ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 0.9 | - | 1.6 | - | 1.6 | - ns |
| | | V _{CC} = 2.3 V to 2.7 V | - | 0.6 | - | 1.7 | - | 1.7 | - ns |
| | | V _{CC} = 3.0 V to 3.6 V | - | 0.6 | - | 1.9 | - | 1.9 | - ns |
| | | SD or RD LOW; see Figure 8 | | | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | - | 4.2 | - | 11.3 | - | 11.5 | - ns |
| | | V _{CC} = 1.4 V to 1.6 V | - | 2.3 | - | 6.2 | - | 6.4 | - ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 1.8 | - | 4.8 | - | 5.0 | - ns |
| C _{PD} | power dissipation capacitance | f = 1 MHz; V _I = GND to V _{CC} | ^[3] | | | | | | |
| | | V _{CC} = 0.8 V | - | 2.8 | - | - | - | - | pF |
| | | V _{CC} = 1.1 V to 1.3 V | - | 2.9 | - | - | - | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | - | 3.0 | - | - | - | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | - | 3.0 | - | - | - | - | pF |
| | | V _{CC} = 2.3 V to 2.7 V | - | 3.5 | - | - | - | - | pF |
| | | V _{CC} = 3.0 V to 3.6 V | - | 3.9 | - | - | - | - | pF |

[1] All typical values are measured at nominal V_{CC}.[2] t_{pd} is the same as t_{PLH} and t_{PHL}.[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$$

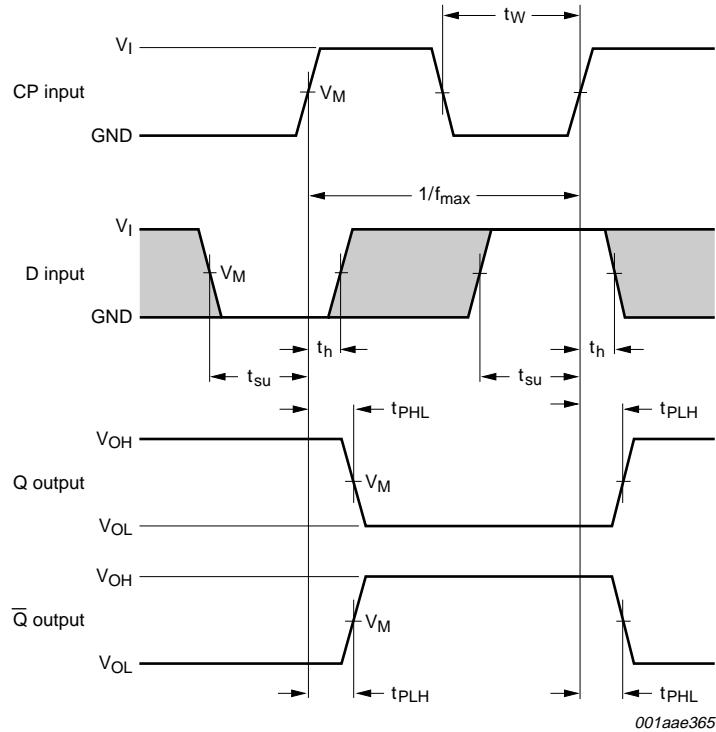
where:

f_i = input frequency in MHz;f_o = output frequency in MHz;C_L = output load capacitance in pF;V_{CC} = supply voltage in V;

N = number of inputs switching;

$$\sum(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$$

12. Waveforms



Measurement points are given in [Table 10](#).

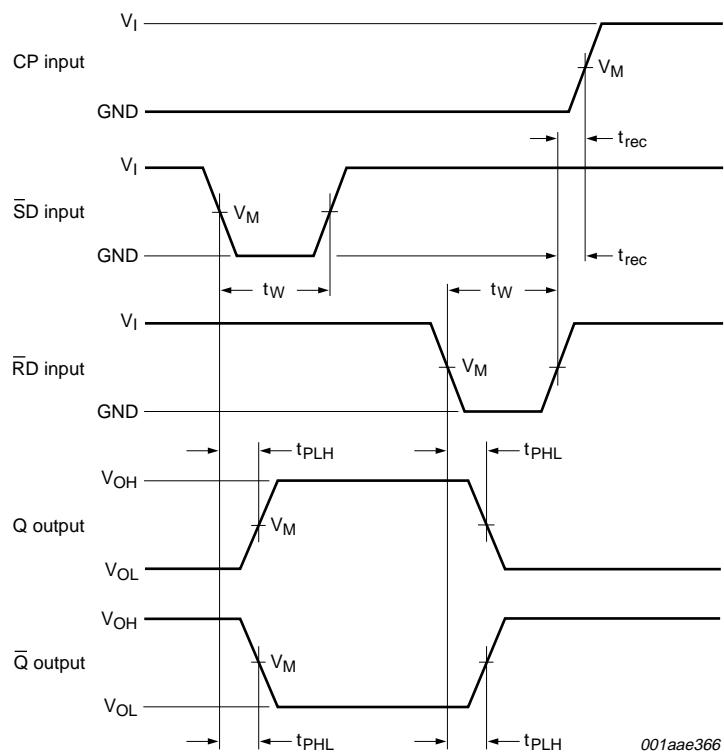
The shaded areas indicate when the input is permitted to change for predictable output performance.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 7. The clock input (CP) to output (Q, \bar{Q}) propagation delays, the data input (D) to clock input (CP) set-up and hold times and the clock input (CP) pulse width and maximum frequency

Table 10. Measurement points

| Supply voltage | Output | Input | | |
|----------------------------|------------------------------|------------------------------|-------------------|------------------------------|
| V_{CC} 0.8 V to 3.6 V | V_M $0.5 \times V_{CC}$ | V_M $0.5 \times V_{CC}$ | V_I V_{CC} | $t_r = t_f$ ≤ 3.0 ns |



001aae366

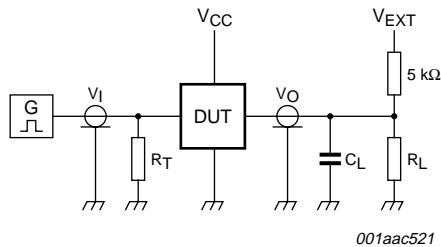
Measurement points are given in [Table 11](#).

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. The set input (\bar{SD}) and reset input (\bar{RD}) to output (Q , \bar{Q}) propagation delays, the set input (\bar{SD}) and reset input (\bar{RD}) pulse widths and the reset input (\bar{RD}) to clock input (CP) recovery time

Table 11. Measurement points

| Supply voltage | Output | Input | | |
|----------------------------|------------------------------|------------------------------|-------------------|--------------------------------------|
| V_{CC} 0.8 V to 3.6 V | V_M $0.5 \times V_{CC}$ | V_M $0.5 \times V_{CC}$ | V_I V_{CC} | $t_r = t_f$ $\leq 3.0 \text{ ns}$ |



Test data is given in [Table 12](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 9. Load circuitry for switching times

Table 12. Test data

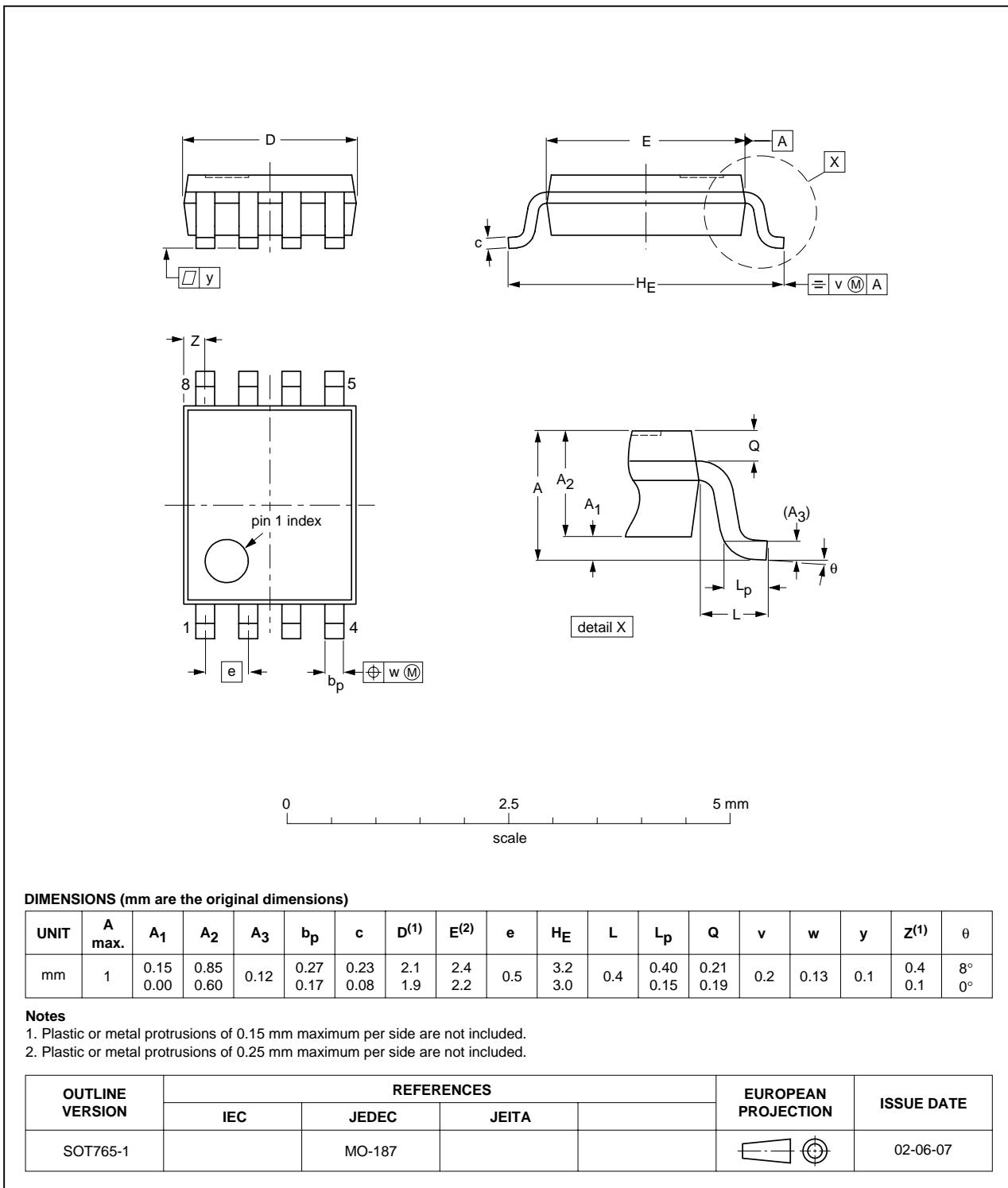
| Supply voltage | Load | | V_{EXT} | | | |
|----------------|------------------------------|----------------------|-----------|--------------------|--------------------|--------------------|
| V_{CC} | C_L | R_L ^[1] | | t_{PLH}, t_{PHL} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open | GND | | 2 × V_{CC} |

[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$, for measuring propagation delays, set-up and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

13. Package outline

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | b _p | c | D ⁽¹⁾ | E ⁽²⁾ | e | H _E | L | L _p | Q | v | w | y | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|-----|----------------|--------------|-----|------|-----|------------------|----------|
| mm | 1 | 0.15 0.00 | 0.85 0.60 | 0.12 | 0.27 0.17 | 0.23 0.08 | 2.1 1.9 | 2.4 2.2 | 0.5 | 3.2 3.0 | 0.4 | 0.40 0.15 | 0.21 0.19 | 0.2 | 0.13 | 0.1 | 0.4 0.1 | 8° 0° |

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|--------|-------|------------------------|------------|
| | IEC | JEDEC | JEITA | | |
| SOT765-1 | | MO-187 | | | 02-06-07 |

Fig 10. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

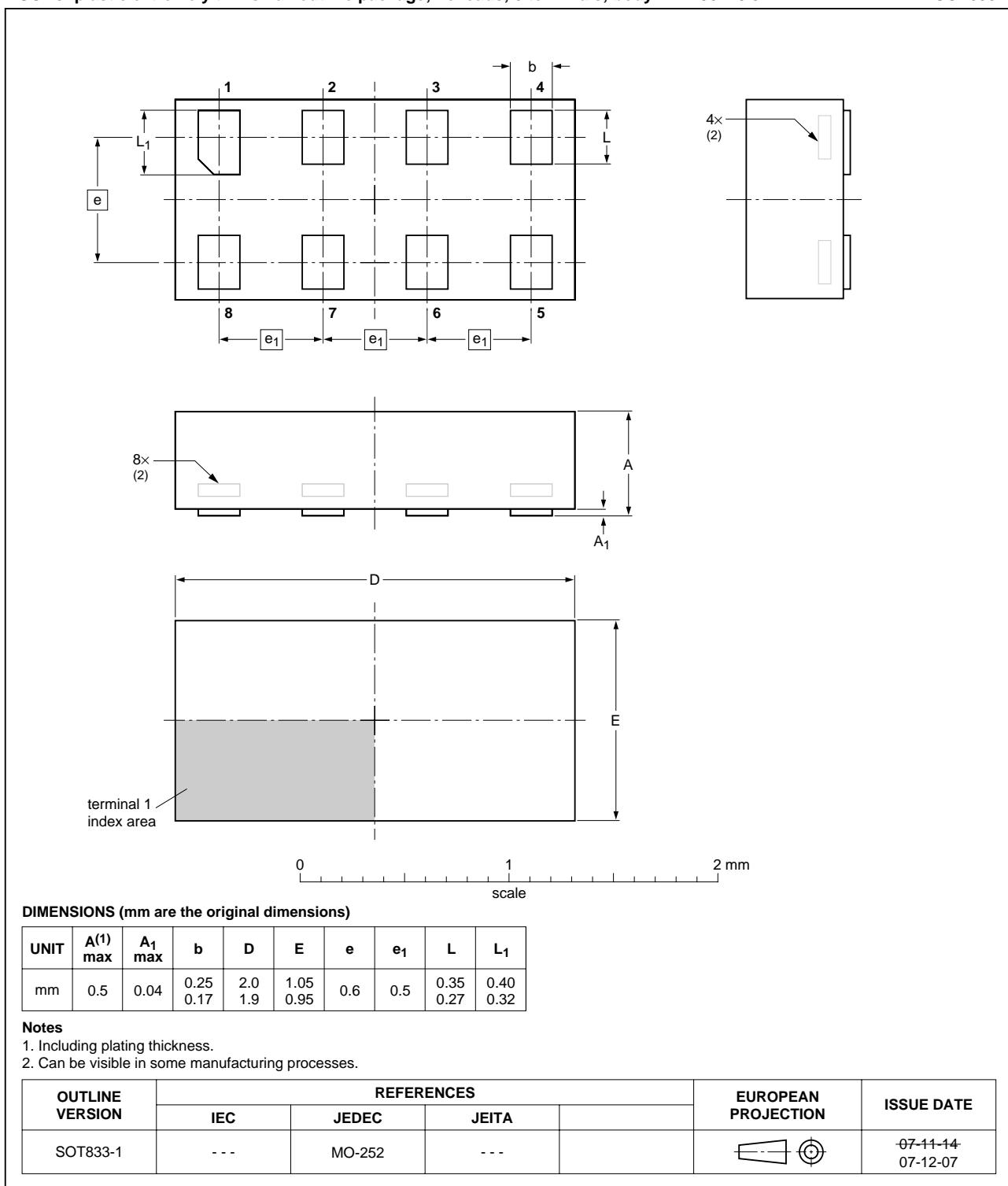


Fig 11. Package outline SOT833-1 (XSON8)

XQFN8U: plastic extremely thin quad flat package; no leads;
8 terminals; UTLP based; body 1.6 x 1.6 x 0.5 mm

SOT902-1

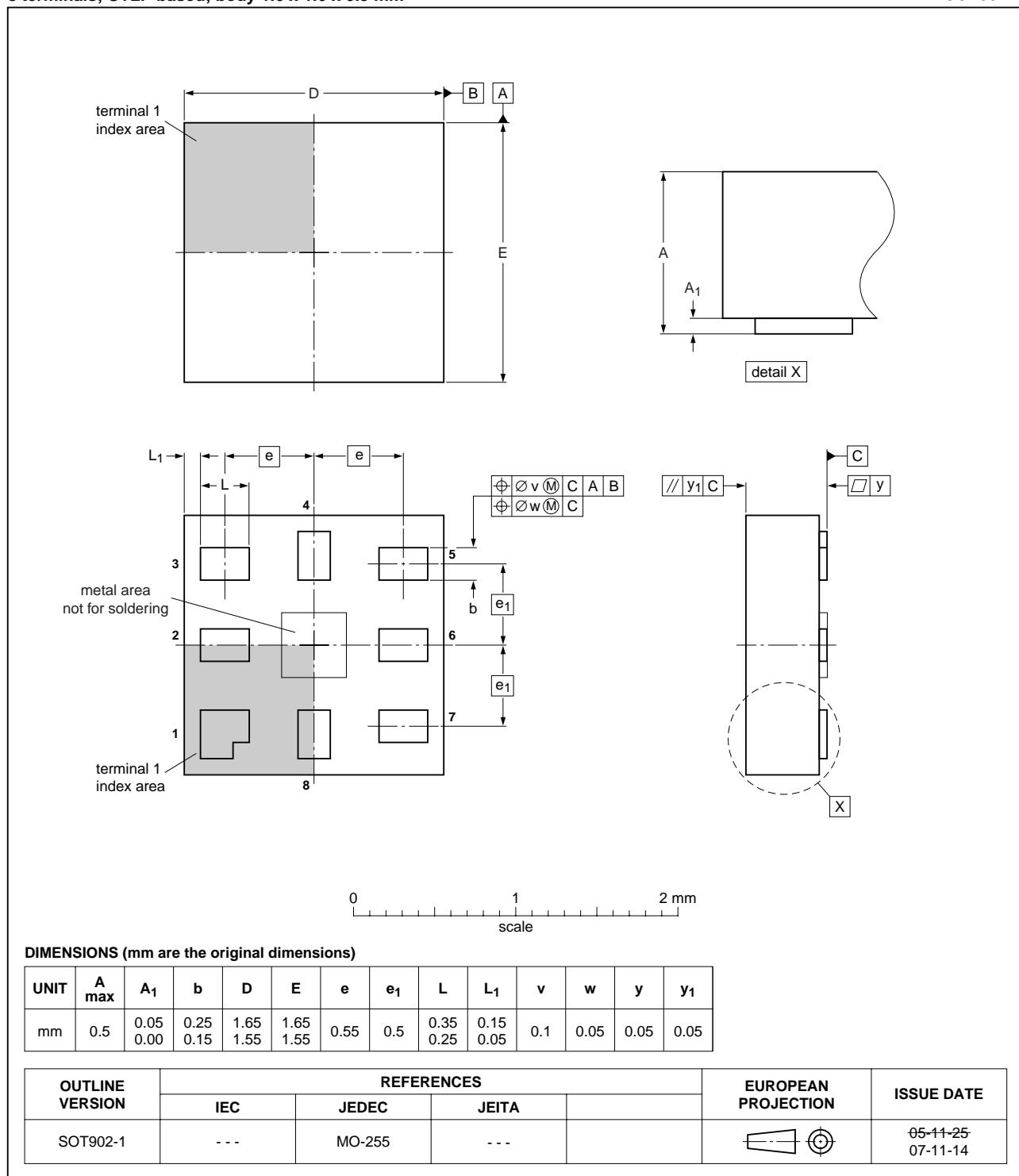


Fig 12. Package outline SOT902-1 (XQFN8U)

14. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
|---------|---|
| CDM | Charged Device Model |
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |

15. Revision history

Table 14. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--------------|--|---------------|-------------|
| 74AUP1G74_3 | 20080207 | Product data sheet | - | 74AUP1G74_2 |
| Modifications: | | • Figure 12 "Package outline SOT902-1 (XQFN8U)": updated | | |
| 74AUP1G74_2 | 20070515 | Product data sheet | - | 74AUP1G74_1 |
| 74AUP1G74_1 | 20060825 | Product data sheet | - | - |

16. Legal information

16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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